

## P-Channel 60-V (D-S) MOSFET

RODUCT SUMMARY								
Part Number	V <sub>(BR)DSS</sub> Min (V)	r <sub>DS(on)</sub> Max (Ω)	V <sub>GS(th)</sub> (V)	I <sub>D</sub> (A)				
TP0610L	-60	10 @ V <sub>GS</sub> = -10 V	−1 to −2.4	-0.18				
TP0610T	-60	10 @ V <sub>GS</sub> = −10 V	−1 to −2.4	-0.12				
VP0610L	-60	10 @ V <sub>GS</sub> = −10 V	−1 to −3.5	-0.18				
VP0610T	-60	10 @ V <sub>GS</sub> = −10 V	−1 to −3.5	-0.12				
BS250	-45	14 @ V <sub>GS</sub> = -10 V	−1 to −3.5	-0.18				

### **FEATURES**

High-Side Switching

Low On-Resistance: 8  $\Omega$ 

Low Threshold: -1.9 V

Fast Switching Speed: 16 ns

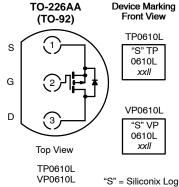
• Low Input Capacitance: 15 pF

### **BENEFITS**

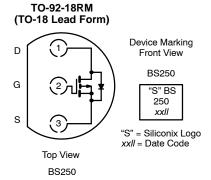
- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- **High-Speed Switching**
- Easily Driven Without Buffer

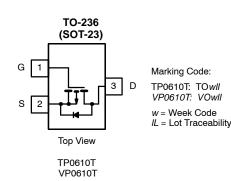
### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Power Supply, Converter Circuits
- Motor Control









ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)										
Parameter  Drain-Source Voltage  Gate-Source Voltage		Symbol	TP0610L	TP0610T	VP0610L	VP0610T	BS250 -45 ±25	Unit		
		$V_{DS}$	-60	-60	-60	-60 ±30				
		$V_{GS}$	±30	±30	±30					
Continuous Drain Current (T <sub>J</sub> = 150°C)	T <sub>A</sub> = 25°C		-0.18	-0.12	-0.18	-0.12	-0.18			
	T <sub>A</sub> = 100°C	- I <sub>D</sub>	-0.11	-0.07	-0.11	-0.07		Α		
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	-0.8	-0.4	-0.8	-0.4				
Power Dissipation	T <sub>A</sub> = 25°C		0.8	0.36	0.8	0.36	0.83	<b>—</b>		
	T <sub>A</sub> = 100°C	P <sub>D</sub>	0.32	0.14	0.32	0.14		W		
Thermal Resistance, Junction-to-Ambient		R <sub>thJA</sub>	156	350	156	350	150	°C/W		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150							

Notes a. Pulse width limited by maximum junction temperature.

For applications information see AN804.

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# TP0610L/T, VP0610L/T, BS250

# Vishay Siliconix



SPECIFICATI	ONS (T <sub>A</sub>	= 25°C UNLESS OTHER	WISE N	OTED	))						
					Limits						
					TP0610L/T		VP0610L/T		BS250		-
Parameter	Symbol	Test Conditions			Min	Max	Min	Max	Min	Мах	Unit
Static											
Drain-Source		$V_{GS} = 0 \text{ V}, I_D = -10 \mu\text{A}$		-70	-60		-60				
Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = -100 \mu A$							-45		V
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -1$ mA		-1.9	-1	-2.4	-1	-3.5	-1	-3.5	
		$V_{DS}$ = 0 V, $V_{GS}$ = $\pm 20$ V				±10		±10			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$				±50					nA
		V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±15 V								±20	1 !
Zero Gate Voltage Drain Current		$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$				-1		-1			
	I <sub>DSS</sub>	V <sub>DS</sub> = -48 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 125°C				-200		-200			μΑ
J		$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V}$								-0.5	1
		$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}$		-180	-50						
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = -10 \text{ V}$	L Suffix	-750			-600				mA
			T Suffix				-220				
	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -25 \text{ mA}$		11		25					
Drain-Source		V <sub>GS</sub> = -10 V, I <sub>D</sub> = -0.5 A	L Suffix	8		10		10			Ω
On-Resistance <sup>b</sup>		$V_{GS} = -10 \text{ V}, I_D = -0.5 \text{ A}, T_J = 125^{\circ}\text{C}$	L Suffix	15		20		20			
		$V_{GS} = -10 \text{ V, } I_D = -0.2 \text{ A}$	T Suffix	6.5		10		10		14	
Forward	-	$V_{DS} = -10 \text{ V}, I_D = -0.5 \text{ A}$	L Suffix	20	80						mS
Transconductance <sup>b</sup>	9fs	$V_{DS} = -10 \text{ V}, I_D = -0.1 \text{ A}$	T Suffix	90	60		70				
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = -0.5 A, V <sub>GS</sub> = 0 V		-1.1							٧
Dynamic	-								•		
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -25 V, V <sub>GS</sub> = 0 V f = 1 MHz		15		60		60			pF
Output Capacitance	C <sub>oss</sub>			10		25		25			
Reverse Transfer Capacitance	C <sub>rss</sub>	I = I MHZ				5		5			
Switching <sup>c</sup>					•	•	•		•	•	
Turn-On Time	t <sub>ON</sub>	$V_{DD} = -25 \text{ V}, R_L = 133 \Omega$ $I_D \cong -0.18 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 25 \Omega$		8						10	ns
Turn-Off Time	t <sub>OFF</sub>			8						10	113

Notes a. For DESIGN AID ONLY, not subject to production testing. b. Pulse test:  $PW \le 300 \ \mu s$  duty cycle  $\le 2\%$ . c. Switching time is essentially independent of operating temperature.

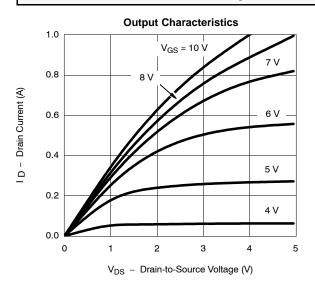
VPDS06

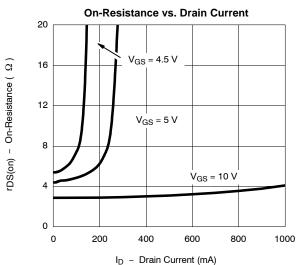


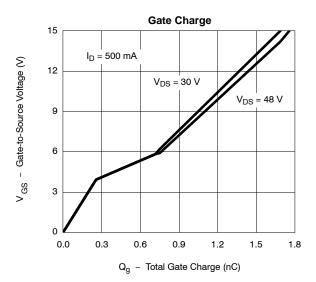


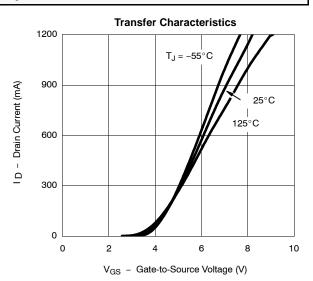
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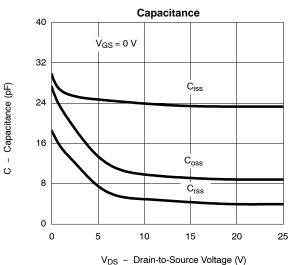
## TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

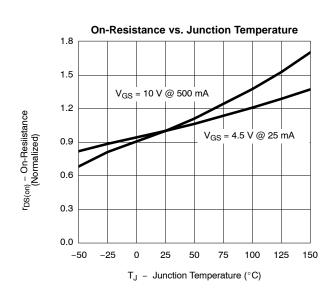










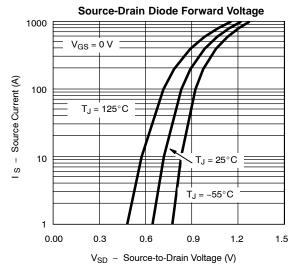


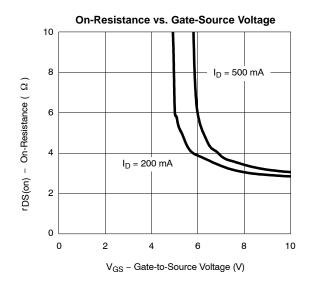
## TP0610L/T, VP0610L/T, BS250

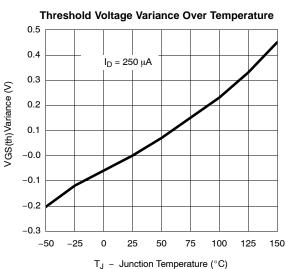
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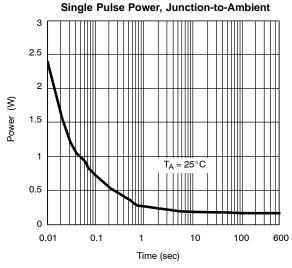


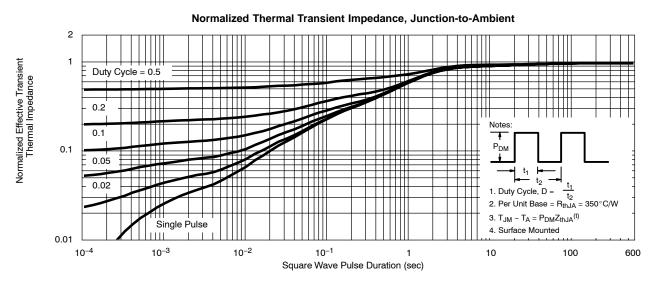
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